



30A Low-Side Ultrafast RF MOSFET Driver

IXRFD630

**Absolute Maximum Ratings**

Parameter	Value
Supply Voltage $V_{CC}$ / $V_{CCIN}$	30V
Input Voltage Level $V_{IN}$	-5V to $V_{CCIN} + 0.3V$
All Other Pins	-0.3V to $(V_{CC}, V_{CCIN}) + 0.3V$
Power Dissipation $T_{AMBIENT} \leq 25C$	2W
$T_{case} \leq 25C$	100W
Storage Temperature	-40°C to 150°C
Soldering Lead Temperature (10 seconds maximum)	300°C

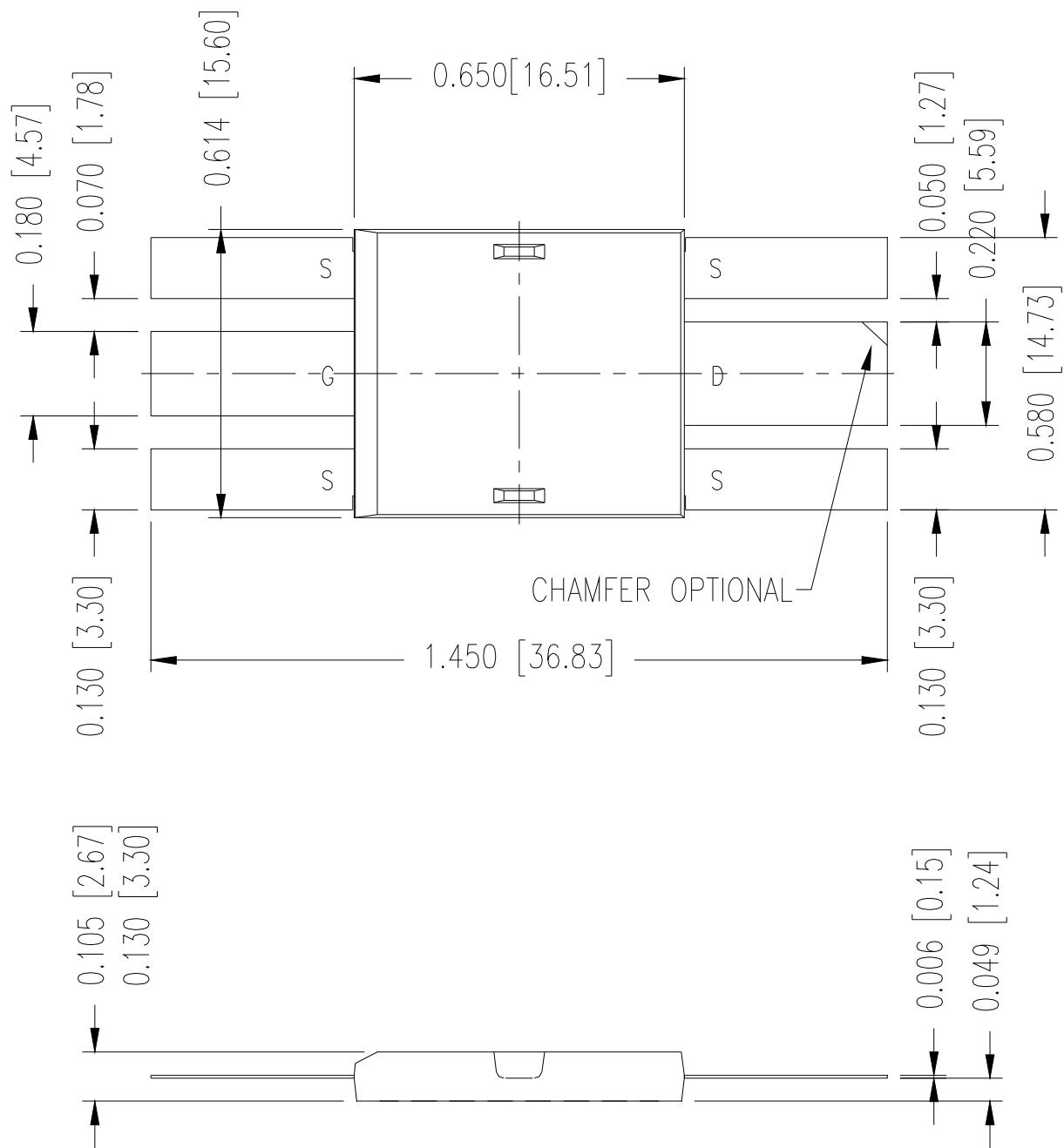
The IXRFD630 is the next generation of IXYSRF drivers and is intended to be a direct, drop-in replacement for the DEIC420.

Parameter	Value
Maximum Junction Temperature	150°C
Operating Temperature Range	-40°C to 85°C
Thermal Impedance (Junction To Case) $\theta_{JC}$	0.25°C/W

**Electrical Characteristics**Unless otherwise noted,  $TA = 25^\circ C$ ,  $8V < V_{CC} = V_{CCIN} < 30V$ .All voltage measurements with respect to DGND. IXRFD615 configured as described in *Test Conditions*.

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
$V_{IH}$	High input voltage		3	3.5		V
$V_{IL}$	Low input voltage			0.8		V
$V_{IN}$	Input voltage range		-5		$V_{CC} + 0.3$	V
$I_{IN}$	Input current	$0V \leq V_{IN} \leq V_{CC}, V_{CCIN}$	-10		10	$\mu A$
$V_{OH}$	High output voltage		$V_{CCIN} - 0.025$			V
$V_{OL}$	Low output voltage			0.025		V
$R_{OH}$	Output resistance @ Output High	$I_{OUT} = 10mA, V_{CC} = 15V$		0.3		$\Omega$
$R_{OL}$	Output resistance @ Output Low	$I_{OUT} = 10mA, V_{CC} = 15V$		0.3		$\Omega$
$I_{PEAK}$	Peak output current	$V_{CC}, V_{CCIN} = 15V$	30			A
$I_{DC}$	Continuous output current			2.5		A
$f_{MAX}$	Maximum frequency	$C_L = 2nF, V_{CC}, V_{CCIN} = 15V$			45	MHz
$t_R$	Rise time	$C_L = 1nF, V_{CC}, V_{CCIN} = 15V, V_{OH} = 2V$ to $12V$	3			ns
		$C_L = 2nF, V_{CC}, V_{CCIN} = 15V, V_{OH} = 2V$ to $12V$	4			ns
$t_F$	Fall time	$C_L = 1nF, V_{CC}, V_{CCIN} = 15V, V_{OH} = 12V$ to $2V$	3			ns
		$C_L = 2nF, V_{CC}, V_{CCIN} = 15V, V_{OH} = 12V$ to $2V$	3.5			ns
$t_{ONDLY}$	On-time propagation delay	$C_L = 2nF, V_{CC} = 15V$		21		ns
$t_{OFFDLY}$	Off-time propagation delay	$C_L = 2nF, V_{CC} = 15V$		23		ns
$PW_{min}$	Minimum pulse width	$FWHM, C_L = 1nF, V_{CC}, V_{CCIN} = 15V$		8		ns
$V_{CC}, V_{CCIN}$	Power supply voltage		8	15	30	V
$I_{CC}$	Power supply current	$V_{CC} = 15V, V_{IN} = 0V$	0	10		$\mu A$
		$V_{CC} = 15V, V_{IN} = 3.5V$	1	3		mA
		$V_{CC} = 15V, V_{IN} = V_{CC}$	0	10		$\mu A$

# Preliminary



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